



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

OLIFF & BERRIDGE,	PLC		Attorney Dock	et No.: <u>04</u>	0090.02	<u>.                                    </u>	<del></del>							
P.O. Box 19928 Alexandria, Virginia Telephone: (703) 836			Date: July 10, 2001											
Facsimile: (703) 836-														
Customer Number:	25044		BOX P	ATENT A	PPLICA	<u>ATION</u>								
Customer Number:	23944	C	ONTINUING	APPLICAT	TION T	RANSMITT	AL							
Director of the U.S. Pa Washington, D.C. 202		ark Office	CONTINUING APPLICATION TRANSMITTAL RULE 1.53(b)											
Sir:														
Transmitted herewith	for filing under 3°	7 C.F.R. §1.53(b) is a												
☐ Con	tinuation	□ Divisional												
application of prior pe	nding Application	n No. <u>09/325,567</u> , file	d <u>June 4, 1999</u>	ه ا										
For (Title):		DEVICE PROVIDED ELECTRONIC DEV DEVICE					AL							
By (Inventors):	Ichio YUDASA	AKA, Tatsuya SHIM	ODA, Sadao F	CANBE and	l Waka	o MIYAZAV	VA							
	ration and Power	of Attorney is attached	d. The attache	d Declaration	on and P	ower of Atto	rney is:							
<del></del>	A copy of the D	eclaration and Power	of Attorney fro	m the paren	t applica	ition. (Used v	with the							
	same or fewer in	nventors and (a) a cop of the prior application	y of the prior a	pplication of	r (b) a re matter )	evised, reform	natted or							
. Пъ	i i	ion and Power of Attor					inventors							
U.	and (a) a copy of	of the prior application	, (b) a revised,	reformatted	l or edite	ed version of	the prior							
		does not contain new	matter, or (c) a	new specifi	cation.)									
2.  The filing	ng fee is calculate	ed below:												
CLAIMS IN THE A														
ANY PRELIMINAR	Y AMENDMEN	IT NOTED BELOW	SMALL	ENTITY		OTHER T								
FOR:	NO. FILED	NO. EXTRA	RATE	FEE	<u>OR</u>	RATE	FEE							
BASIC FEE				\$ 355	OR		\$ 710							
TOTAL CLAIMS	51 - 20	= *31	x 9=	\$	OR	x 18	\$ 558							
INDEP CLAIMS	5 - 3	= *2	x 40 =	\$	OR	x 80	\$ 160							
☐ MULTIPLE DEF	PENDENT CLAI	MS PRESENTED	+135 =	\$	<u>OR</u>	+270	\$ 0							
* If the difference			TOTAL	s	<u>OR</u>	TOTAL	\$1428							
							L							
3.	No. <b>120770</b> in the	amount of \$1,428.00	to cover the fi	ling fee is a	tached.	The Directo	r is							
hereby a	authorized to cha	rge any other fees that	may be require	ed to comple	ete this f	iling, or to cr	edit							
any ove attached		oosit Account No. 15-0	1461. Two dup	licate copie	s of this	sheet are								
4. Cancel		the application before	calculating the	filing fee.	At least	one independ	lent claim							
	ed for filing purp		J	<u>.</u>										
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necessary for Charge any fee														
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5.	$\boxtimes$	Amend the specification by inserting before the first line the sentence:
		This is a Continuation Division Continuation-in-Part of Application No. <u>09/325,567</u> filed <u>June 4, 1999</u> , which is a <u>Rule 1.53(b) Continuation of U.S.S.N. 08/983,036</u> , which in turn is a <u>U.S. National Stage Application of PCT/JP97/01618</u> . The entire disclosure of the prior application(s)
		is hereby incorporated by reference herein in its entirety
6.	$\boxtimes$	Drawings (Fig(s). <u>1-44</u> ) are attached.
		Use Figure for front page of Publication.
7.	$\boxtimes$	Priority of foreign application(s) No. 8-120653 filed May 15, 1996 in Japan; 8-248071 filed September 19, 1996 in Japan; 8-303387 filed November 14, 1996 in Japan are claimed under 35 U.S.C. §119 and/or §365(b).
		The certified copy was filed in prior Application No on
		A certified copy of the above foreign application(s) is filed herewith.
8.		Priority of U.S. Provisional Application(s) No filed is claimed under 35 U.S.C. §119.
		Amend the specification by inserting before the first line the sentence:
		This nonprovisional application claims the benefit of U.S. Provisional Application(s) No filed
9.	$\boxtimes$	The prior application is assigned of record to <u>Seiko Epson Corporation</u> recorded at Reel <u>9149</u> , Frame <u>0850</u> .
10.		This application is filed by fewer than all the inventors named in the prior application (37 C.F.R §1.53(b)(1)). Delete the following inventor(s) named in the prior application:
11.	$\boxtimes$	A Preliminary Amendment is attached. Claims added by this Amendment are properly numbered consecutively beginning with the number next following the highest numbered claim in the application.
11. 12.	⊠ ⊠	A Preliminary Amendment is attached. Claims added by this Amendment are properly numbered consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.
		consecutively beginning with the number next following the highest numbered claim in the application.
12.		consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.
12.		consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.  Small entity status:
12.		consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.  Small entity status:  a. Entitlement to small entity status is asserted.
12. 13.		consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.  Small entity status:  a. Entitlement to small entity status is asserted.  b. Small entity status is no longer claimed.
12. 13.		consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.  Small entity status:  a. Entitlement to small entity status is asserted.  b. Small entity status is no longer claimed.  Other:  This application is NOT to be published under 35 U.S.C. 112(b). The undersigned attorney or agent hereby certifies that the invention disclosed in this application has not been and will not be the subject of an application filed in another country, or under a multilateral international agreement, that requires publication at eighteen months after filing.  The power of attorney in the application is to James A. Oliff, Registration No. 27,075, William P. Berridge, Registration No. 30,024, Kirk M. Hudson, Registration No. 27,562, Thomas J. Pardini, Registration No. 30,411, Edward P. Walker, Registration No. 31,450, Robert A. Miller, Registration No. 32,771, Mario A. Costantino, Registration No. 33,565, Stephen J. Roe, Registration No. 34,463, Joel S. Armstrong, Registration No. 36,430, Christopher W. Brown, Registration No. 38,025, and/or Richard E. Rice, Registration No. 31,560.
12. 13. 14. 15.		consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.  Small entity status:  a. Entitlement to small entity status is asserted.  b. Small entity status is no longer claimed.  Other:  This application is NOT to be published under 35 U.S.C. 112(b). The undersigned attorney or agent hereby certifies that the invention disclosed in this application has not been and will not be the subject of an application filed in another country, or under a multilateral international agreement, that requires publication at eighteen months after filing.  The power of attorney in the application is to James A. Oliff, Registration No. 27,075, William P. Berridge, Registration No. 30,024, Kirk M. Hudson, Registration No. 27,562, Thomas J. Pardini, Registration No. 30,411, Edward P. Walker, Registration No. 31,450, Robert A. Miller, Registration No. 32,771, Mario A. Costantino, Registration No. 33,565, Stephen J. Roe, Registration No. 34,463, Joel S. Armstrong, Registration No. 36,430, Christopher W. Brown, Registration No. 38,025, and/or Richard E. Rice, Registration No. 31,560.  a. The power appears in the attached Declaration and Power of Attorney.
12. 13. 14. 15.		consecutively beginning with the number next following the highest numbered claim in the application.  An Information Disclosure Statement is attached.  Small entity status:  a. Entitlement to small entity status is asserted.  b. Small entity status is no longer claimed.  Other:  This application is NOT to be published under 35 U.S.C. 112(b). The undersigned attorney or agent hereby certifies that the invention disclosed in this application has not been and will not be the subject of an application filed in another country, or under a multilateral international agreement, that requires publication at eighteen months after filing.  The power of attorney in the application is to James A. Oliff, Registration No. 27,075, William P. Berridge, Registration No. 30,024, Kirk M. Hudson, Registration No. 27,562, Thomas J. Pardini, Registration No. 30,411, Edward P. Walker, Registration No. 31,450, Robert A. Miller, Registration No. 32,771, Mario A. Costantino, Registration No. 33,565, Stephen J. Roe, Registration No. 34,463, Joel S. Armstrong, Registration No. 36,430, Christopher W. Brown, Registration No. 38,025, and/or Richard E. Rice, Registration No. 31,560.

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Respectfully submitted,

James A. Oliff Registration No. 27,075

Eric D. Morehouse Registration No. 38,565

Support in Priority Doc JP 8-120653	P24, ¶42 through page 26 ¶44 describes	the TFT and its components (by	reference to Figures 3 and 4, including	an insulating substrate 401, a gate	electrode 405, gate insulating film 404,	semiconducting channel region 403,	source contacts 403S, and drain contacts	403D), wherein the channel region is	formed from polymer silane having	various plural monomer units as the	material forming the polymer	semiconducting layer;	P39, ¶39 describes using ink-jetting to	form the channel and the insulating film.										
Support in 09/901,126	Fig. 38(B), P93, L1-4:	reverse stagger-type TFT.	Fig. 38(B), P93, L1-P94, L21:	<ul> <li>insulating substrate 410 and</li> </ul>	protective underlayer 411.	- gate electrode 415.	- gate insulating film 413.	- amorphous silicon film 417.	- source/drain electrodes 431, 492.	P94, L22, P95, L4:	Semiconducting layer can be	formed of a coating film as in the	first embodiment.	P41-42: using polymer silane having	various plural monomer units as	the material forming the	conductive layer; P58, L5-9: using	ink-jetting to deposit the material	forming the conductive layer.	Figs. 14-16; P56, L1-P59, L21:	Ink-jet printing also, applicable to the	silicon film forming the channel	region (region 14C between 14S and	14D in Fig. 10). See P58, L5-9.
Claims in 09/901,126	82. A process of forming thin	film field effect transistors	comprising the steps of:	forming a gate electrode on	a substrate:	forming a gate insulator	over said gate electrode:	forming a polymer	semiconducting layer on said	insulator by ink-jet printing; and	forming source and drain	contacts on said semiconducting	laver									•		
Claim in '196 Patent	23. A process of forming thin	film field effect transistors	comprising the steps of:	forming a gate electrode on	a substrate:	forming a gate insulator	over said gate electrode:	forming a nolymer	semiconducting layer on said	insulator by ink-iet printing: and	forming source and drain	200	laver											
Count	Count 3. A process of forming	thin film field effect transistors	comprising the steps of:	forming a gate electrode on	a cubetrate.	forming a gate inculator	over said gate electrode.	forming a semiconducting	louning a semiconducting	rajer on Said mounted by mr. Jet	forming source and drain		lover	idyet.										